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## **ON Semiconductor**®

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Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (\_), the underscore (\_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (\_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at <a href="https://www.onsemi.com">www.onsemi.com</a>. Please email any questions regarding the system integration to <a href="https://www.onsemi.com">Fairchild\_questions@onsemi.com</a>.

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January 2014



SEMICONDUCTOR

## FSAM20SH60A Motion SPM<sup>®</sup> 2 Series

## Features

- UL Certified No. E209204 (UL1557)
- 600 V 20 A 3-Phase IGBT Inverter with Integral Gate Drivers and Protection
- Low-Loss, Short-Circuit Rated IGBTs
- Low Thermal Resistance Using Ceramic Substrate
- Separate Open-Emitter Pins from Low Side IGBTs for Three-Phase Current Sensing
- Single-Grounded Power Supply
- Optimized for 15 kHz Switching Frequency
- Built-in NTC Thermistor for Temperature Monitoring
- Inverter Power Rating of 1.5 kW / 100~253 VAC
- Adjustable Current Protection Level via Selection of Sense-IGBT Emitter's External Rs
- Isolation Rating: 2500 V<sub>rms</sub> / min.

## Applications

• Motion Control - Home Appliance / Industrial Motor

## Resource

• AN-9043 - Motion SPM® 2 Series User's Guide

## **General Description**

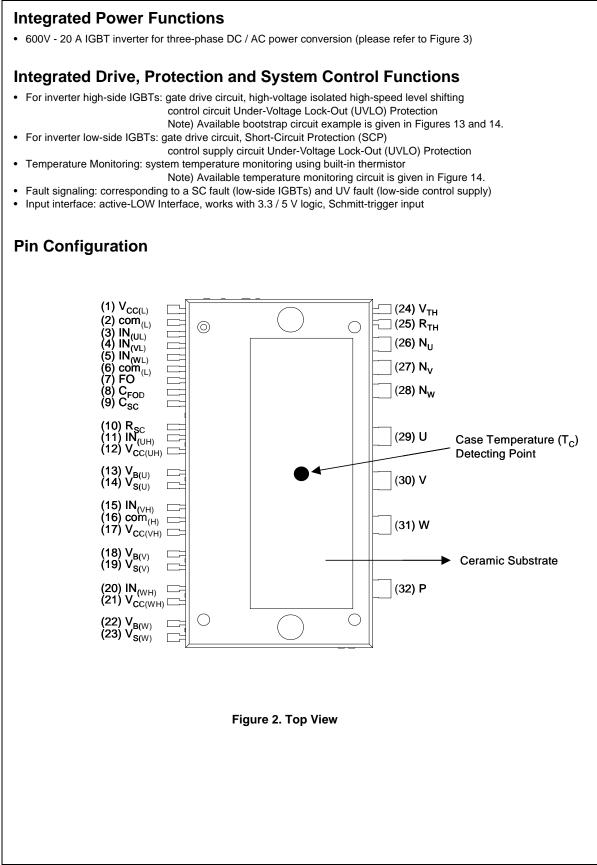
FSAM20SH60A is a Motion SPM<sup>®</sup> 2 module providing a fully-featured, high-performance inverter stage for AC Induction, BLDC, and PMSM motors. These modules integrate optimized gate drive of the built-in IGBTs to minimize EMI and losses, while also providing multiple on-module protection features including under-voltage lockouts, overcurrent shutdown, thermal monitoring, and fault reporting. The built-in, high-speed HVIC requires only a single supply voltage and translates the incoming logic-level gate inputs to the high-voltage, high-current drive signals required to properly drive the module's internal IGBTs. Separate negative IGBT terminals are available for each phase to support the widest variety of control algorithms.



### Figure 1. Package Overview

## Package Marking and Ordering Information

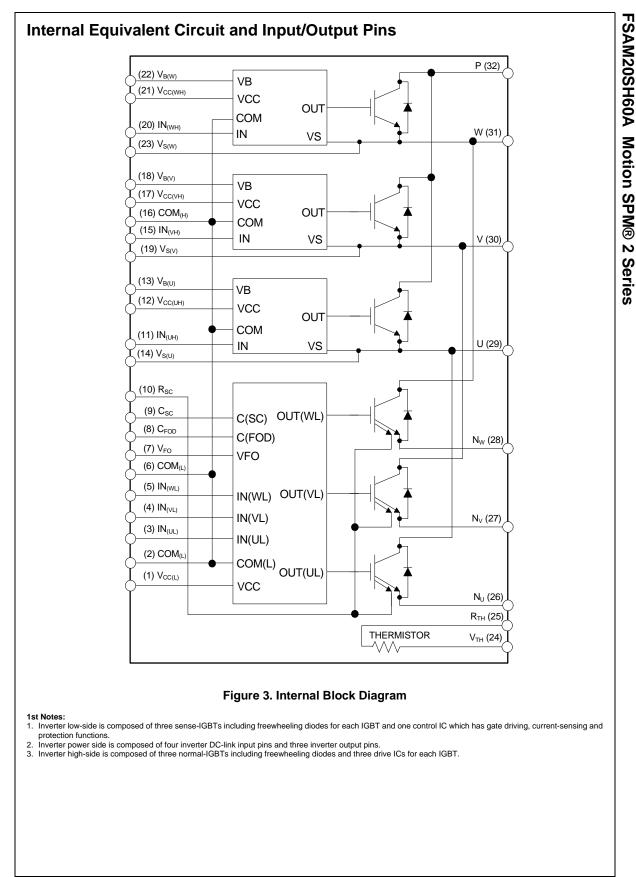
Device	Device Marking	evice Marking Package		Quantity	
FSAM20SH60A	FSAM20SH60A	S32AA-032	Rail	8	



FSAM20SH60A Motion SPM® 2 Series

## **Pin Descriptions**

Pin Number	Pin Name	Pin Description
1	V <sub>CC(L)</sub>	Low-Side Common Bias Voltage for IC and IGBTs Driving
2	COM <sub>(L)</sub>	Low-Side Common Supply Ground
3	IN <sub>(UL)</sub>	Signal Input Terminal for Low-Side U-Phase
4	IN <sub>(VL)</sub>	Signal Input Terminal for Low-Side V-Phase
5	IN <sub>(WL)</sub>	Signal Input Terminal for Low-Side W-Phase
6	COM <sub>(L)</sub>	Low-Side Common Supply Ground
7	V <sub>FO</sub>	Fault Output
8	C <sub>FOD</sub>	Capacitor for Fault Output Duration Selection
9	C <sub>SC</sub>	Capacitor (Low-Pass Filter) for Short-Circuit Current Detection Input
10	R <sub>SC</sub>	Resistor for Short-Circuit Current Detection
11	IN <sub>(UH)</sub>	Signal Input for High-Side U-Phase
12	V <sub>CC(UH)</sub>	High-Side Bias Voltage for U-Phase IC
13	V <sub>B(U)</sub>	High-Side Bias Voltage for U-Phase IGBT Driving
14	V <sub>S(U)</sub>	High-SideBias Voltage Ground for U-Phase IGBT Driving
15	IN <sub>(VH)</sub>	Signal Input for High-Side V-Phase
16	COM(H)	High-Side Common Supply Ground
17	V <sub>CC(VH)</sub>	High-Side Bias Voltage for V-Phase IC
18	V <sub>B(V)</sub>	High-Side Bias Voltage for V-Phase IGBT Driving
19	V <sub>S(V)</sub>	High-Side Bias Voltage Ground for V-Phase IGBT Driving
20	IN <sub>(WH)</sub>	Signal Input for High-side W-Phase
21	V <sub>CC(WH)</sub>	High-Side Bias Voltage for W-Phase IC
22	V <sub>B(W)</sub>	High-Side Bias Voltage for W-Phase IGBT Driving
23	V <sub>S(W)</sub>	High-Side Bias Voltage Ground for W-Phase IGBT Driving
24	V <sub>TH</sub>	Thermistor Bias Voltage
25	R <sub>TH</sub>	Series Resistor for the Use of Thermistor (Temperature Detection)
26	NU	Negative DC-Link Input Terminal for U-Phase
27	N <sub>V</sub>	Negative DC-Link Input Terminal for V-Phase
28	N <sub>W</sub>	Negative DC-Link Input Terminal for W-Phase
29	U	Output for U-Phase
30	V	Output for V-Phase
31	W	Output for W-Phase
32	Р	Positive DC-Link Input



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ltem	Symbol	Condition	Rating	Unit
Supply Voltage	V <sub>DC</sub>	Applied to DC-Link	450	V
Supply Voltage (Surge)	V <sub>PN(Surge)</sub>	Applied between P and N	500	V
Collector - Emitter Voltage	V <sub>CES</sub>		600	V
Each IGBT Collector Current	± I <sub>C</sub>	$T_{\rm C} = 25^{\circ}{\rm C}$	20	A
Each IGBT Collector Current	± I <sub>C</sub>	$T_{\rm C} = 100^{\circ}{\rm C}$	14	A
Each IGBT Collector Current (Peak)	± I <sub>CP</sub>	$T_C = 25^{\circ}C$ , Under 1ms Pulse Width	40	A
Collector Dissipation	P <sub>C</sub>	T <sub>C</sub> = 25°C per Chip	59	W
Operating Junction Temperature	TJ	(2nd Note 1)	-20 ~ 125	°C

2nd Notes: 1. It would be recommended that the average junction temperature should be limited to  $T_J \le 125^{\circ}C$  (at  $T_C \le 100^{\circ}C$ ) in order to guarantee safe operation.

### **Control Part**

Item	Symbol	Condition	Rating	Unit
Control Supply Voltage	V <sub>CC</sub>	Applied between $V_{CC(UH)}$ , $V_{CC(VH)}$ , $V_{CC(WH)}$ - $COM_{(H)}$ , $V_{CC(L)}$ - $COM_{(L)}$	20	V
High-Side Control Bias Voltage	V <sub>BS</sub>	Applied between $V_{B(U)}$ - $V_{S(U)}$ , $V_{B(V)}$ - $V_{S(V)}$ , $V_{B(W)}$ - $V_{S(W)}$	20	V
Input Signal Voltage	V <sub>IN</sub>	Applied between $IN_{(UH)}$ , $IN_{(VH)}$ , $IN_{(WH)}$ - $COM_{(H)}$ $IN_{(UL)}$ , $IN_{(VL)}$ , $IN_{(WL)}$ - $COM_{(L)}$	-0.3 ~ V <sub>CC</sub> +0.3	V
Fault Output Supply Voltage	V <sub>FO</sub>	Applied between V <sub>FO</sub> - COM <sub>(L)</sub>	-0.3 ~ V <sub>CC</sub> +0.3	V
Fault Output Current	I <sub>FO</sub>	Sink Current at V <sub>FO</sub> Pin	5	mA
Current-Sensing Input Voltage	V <sub>SC</sub>	Applied between C <sub>SC</sub> - COM <sub>(L)</sub>	-0.3 ~ V <sub>CC</sub> +0.3	V

### **Total System**

Item	Symbol	Condition	Rating	Unit V	
Self-Protection Supply Voltage Limit (Short-Circuit Protection Capability)	V <sub>PN(PROT)</sub>	Applied to DC-Link, $V_{CC} = V_{BS} = 13.5 \sim 16.5 V$ $T_J = 125^{\circ}C$ , Non-Repetitive, < 6 µs	400		
Module Case Operation Temperature	Т <sub>С</sub>	See Figure 2	-20 ~ 100	°C	
Storage Temperature	T <sub>STG</sub>		-20 ~ 125	°C	
Isolation Voltage	V <sub>ISO</sub>	60Hz, Sinusoidal, AC 1 Minute, Connect Pins to Heat Sink Plate	2500	V <sub>rms</sub>	

### **Thermal Resistance**

Item	Symbol	Condition	Min.	Тур.	Max.	Unit
Junction to Case Thermal	R <sub>th(j-c)Q</sub>	Inverter IGBT Part (per 1/6 module)	-	-	2.10	°C/W
Resistance	R <sub>th(j-c)F</sub>	Inverter FWDi Part (per 1/6 module)	-	-	3.20	°C/W
Contact Thermal	R <sub>th(c-f)</sub>	Ceramic Substrate (per 1 Module)	-	-	0.06	°C/W
Resistance		Thermal Grease Applied (2nd Note 3)				

 $\begin{array}{l} \mbox{2nd Notes:} \\ \mbox{2. For the measurement point of case temperature(T_C), please refer to Figure 2.} \\ \mbox{3. The thickness of thermal grease should not be more than 100 $\mu$m}. \end{array}$ 

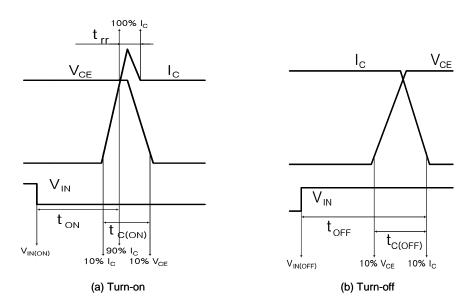
## **Electrical Characteristics**

**Inverter Part** ( $T_J$  = 25°C, unless otherwise specified.)

Item	Symbol	Conc	lition	Min.	Тур.	Max.	Unit
Collector - Emitter	V <sub>CE(SAT)</sub>	$V_{CC} = V_{BS} = 15 V$ $V_{IN} = 0 V$	I <sub>C</sub> = 20 A, T <sub>J</sub> = 25°C	-	-	2.50	V
Saturation Voltage	. ,	$V_{IN} = 0 V$	I <sub>C</sub> = 20 A, T <sub>J</sub> = 125°C	-	-	2.60	V
FWDi Forward Voltage	V <sub>FM</sub>	V <sub>IN</sub> = 5 V	I <sub>C</sub> = 20 A, T <sub>J</sub> = 25°C	-	-	2.50	V
			I <sub>C</sub> = 20 A, T <sub>J</sub> = 125°C	-	-	2.30	V
Switching Times	t <sub>ON</sub>	$V_{PN} = 300 \text{ V}, V_{CC} = V_{BS} =$	= 15 V	-	0.35	-	μS
	t <sub>C(ON)</sub>	$I_{C} = 20 \text{ A}, T_{J} = 25^{\circ}\text{C}$		-	0.16	-	μS
	t <sub>OFF</sub>	$V_{IN} = 5 V \leftrightarrow 0V$ , Inductive (High, Low-side)	Load	-	0.75	-	μS
	t <sub>C(OFF)</sub>	(Trigh, Low-side)		-	0.23	-	μS
	t <sub>rr</sub>	(2nd Note 4)		-	0.13	-	μS
Collector - Emitter Leakage Current	I <sub>CES</sub>	$V_{CE} = V_{CES}, T_{J} = 25^{\circ}C$		-	-	250	μA

2nd Notes:

to total GPF include the propagation delay time of the internal drive IC. t<sub>C(ON)</sub> and t<sub>C(OFF)</sub> are the switching time of IGBT itself under the given gate driving condition internally. For the detailed information, please see Figure 4.





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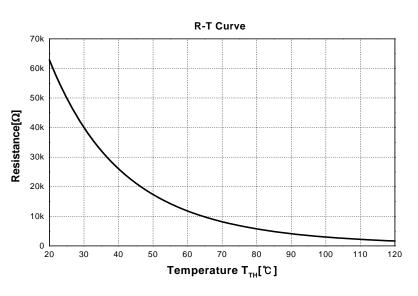
## **Electrical Characteristics** ( $T_J = 25^{\circ}C$ , unless otherwise specified.)

## **Control Part**

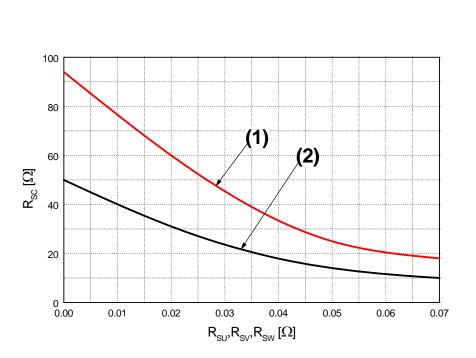
Item	Symbol	(	Condition	Min.	Тур.	Max.	Unit
Quiescent V <sub>CC</sub> Supply Cur- rent	I <sub>QCCL</sub>	V <sub>CC</sub> = 15 V IN <sub>(UL, VL, WL)</sub> = 5V	V <sub>CC(L)</sub> - COM <sub>(L)</sub>	-	-	26	mA
	I <sub>QCCH</sub>	V <sub>CC</sub> = 15 V IN <sub>(UH, VH, WH)</sub> = 5V	V <sub>CC(UH)</sub> , V <sub>CC(VH)</sub> , V <sub>CC(WH)</sub> - COM <sub>(H)</sub>	-	-	130	μA
Quiescent V <sub>BS</sub> Supply Cur- rent	I <sub>QBS</sub>	V <sub>BS</sub> = 15 V IN <sub>(UH, VH, WH)</sub> = 5V	$ \begin{array}{l} V_{B(U)} \text{ - } V_{S(U)}, \ V_{B(V)} \text{ - } V_{S(V)}, \\ V_{B(W)} \text{ - } V_{S(W)} \end{array} $	-	-	420	μΑ
Fault Output Voltage	Dutput Voltage $V_{FOH}$ $V_{SC} = 0 V$ , $V_{FO}$ Circuit: 4.7 k $\Omega$ to 5 V Pull-up		4.5	-	-	V	
	V <sub>FOL</sub>	V <sub>SC</sub> = 1 V, V <sub>FO</sub> Circuit	: 4.7 k $\Omega$ to 5 V Pull-up	-	-	1.1	V
Short-Circuit Trip Level	V <sub>SC(ref)</sub>	V <sub>CC</sub> = 15 V (Note 5)			0.51	0.56	V
Sensing Voltage of IGBT Current	V <sub>SEN</sub>	$\rm R_{SC}$ = 50 $\Omega, ~\rm R_{SU}$ = $\rm R_{SV}$ = $\rm R_{SW}$ = 0 $\Omega$ and $\rm I_{C}$ = 30 A (See a Figure 6)			0.51	0.56	V
Supply Circuit Under-	UV <sub>CCD</sub>	Detection Level		11.5	12.0	12.5	V
Voltage Protection	UV <sub>CCR</sub>	Reset Level Detection Level		12.0	12.5	13.0	V
	UV <sub>BSD</sub>			7.3	9.0	10.8	V
	UV <sub>BSR</sub>	Reset Level		8.6	10.3	12.0	V
Fault Output Pulse Width	t <sub>FOD</sub>	C <sub>FOD</sub> = 33 nF (2nd No	ote 6)	1.4	1.8	2.0	ms
ON Threshold Voltage	V <sub>IN(ON)</sub>	High-Side	Applied between IN <sub>(UH)</sub> ,	-	-	0.8	V
OFF Threshold Voltage	V <sub>IN(OFF)</sub>		$IN_{(VH)}, IN_{(WH)} - COM_{(H)}$	3.0	-	-	V
ON Threshold Voltage	V <sub>IN(ON)</sub>	Low-Side	Applied between IN <sub>(UL)</sub> ,	-	-	0.8	V
OFF Threshold Voltage	V <sub>IN(OFF)</sub>		IN <sub>(VL)</sub> , IN <sub>(WL)</sub> - COM <sub>(L)</sub>	3.0	-	-	V
Resistance of Thermistor	R <sub>TH</sub>	@ T <sub>TH</sub> = 25°C (2nd No	ote 7, Figure 5)	-	50	-	kΩ
		@ T <sub>TH</sub> = 100°C (2nd N	Note 7, Figure 5)	-	3.4	-	kΩ

### 2nd Notes:

2nd Notes:
5. Short-circuit protection is functioning only at the low-sides. It would be recommended that the value of the external sensing resistor (R<sub>SC</sub>) should be selected around 50 Ω in order to make the SC trip-level of about 30A at the shunt resistors (R<sub>SU</sub>, R<sub>SW</sub>, R<sub>SW</sub>) of 0 Ω. For the detailed information about the relationship between the external sensing resistor (R<sub>SC</sub>) and the shunt resistors (R<sub>SU</sub>, R<sub>SW</sub>, R<sub>SW</sub>), please see Figure 6.
6. The fault-out pulse width t<sub>FOD</sub> depends on the capacitance value of C<sub>FOD</sub> according to the following approximate equation: C<sub>FOD</sub> = 18.3 x 10<sup>-6</sup> x t<sub>FOD</sub> [F]
7. T<sub>TH</sub> is the temperature of thermistor itself. To know case temperature (T<sub>C</sub>), please make the experiment considering your application.





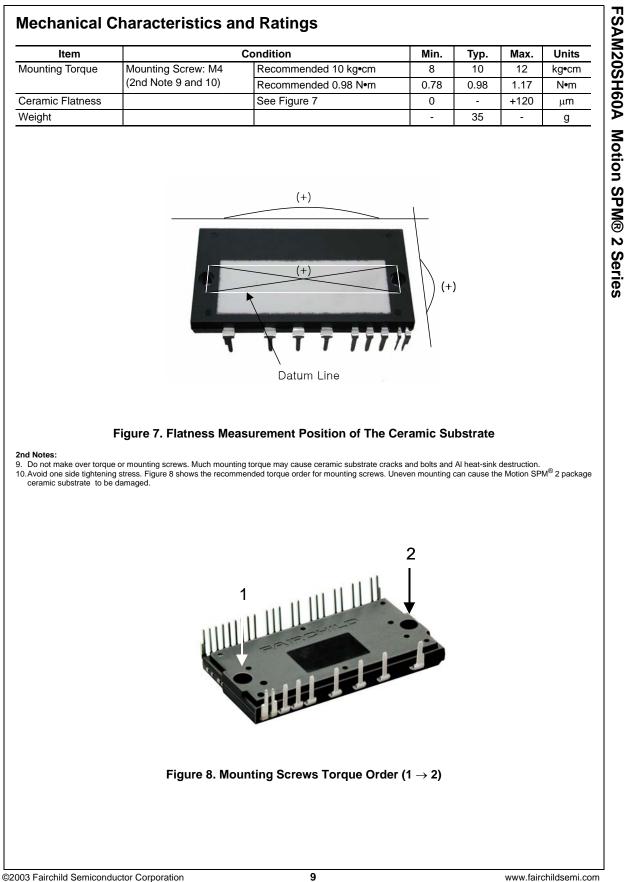


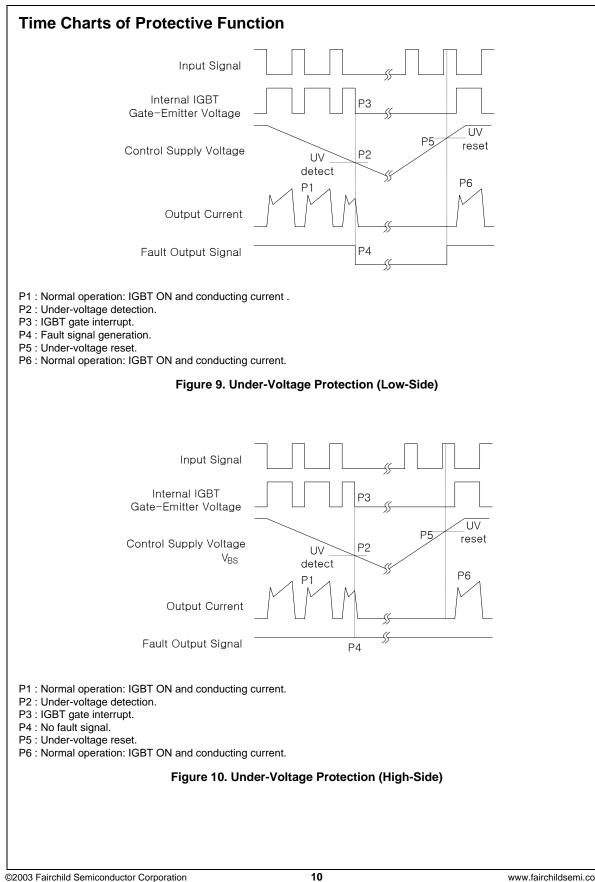


## **Recommended Operating Conditions**

Item	Symbol	Condition	Min.	Тур.	Max.	Unit
Supply Voltage	V <sub>PN</sub>	Applied between P - N <sub>U</sub> , N <sub>V</sub> , N <sub>W</sub>	-	300	400	V
Control Supply Voltage	V <sub>CC</sub>	Applied between $V_{CC(UH)}$ , $V_{CC(VH)}$ , $V_{CC(WH)}$ - 1 COM <sub>(H)</sub> , $V_{CC(L)}$ - COM <sub>(L)</sub>		15.0	16.5	V
High-side Bias Voltage	V <sub>BS</sub>	Applied between $V_{B(U)} - V_{S(U)}$ , $V_{B(V)} - V_{S(V)}$ , 1 $V_{B(W)} - V_{S(W)}$		15.0	18.5	V
Blanking Time for Preventing Arm-short	t <sub>dead</sub>	For Each Input Signal	3.0	-	-	μS
PWM Input Signal	f <sub>PWM</sub>	$T_C \le 100^{\circ}C, T_J \le 125^{\circ}C$	-	15	-	kHz
Minimum Input Pulse Width	PW <sub>IN(OFF)</sub>	$\begin{array}{l} 200 \leq V_{PN} \leq 400  \text{V},  13.5 \leq V_{CC} \leq 16.5  \text{V}, \\ 13.0 \leq V_{BS} \leq 18.5  \text{V},  0 \leq I_C \leq 40  \text{A}, \\ -20 \leq T_J \leq 125 ^{\circ} \text{C} \\ \text{V}_{IN} = 5  \text{V} \leftrightarrow 0  \text{V},  \text{Inductive Load}  (\text{2nd Note 8}) \end{array}$	3	-	-	μs
Input ON Threshold Voltage	V <sub>IN(ON)</sub>	$\begin{array}{l} \mbox{Applied between IN}_{(UH)}, \mbox{IN}_{(VH)}, \mbox{IN}_{(WH)} - \\ \mbox{COM}_{(H)}, \mbox{IN}_{(UL)}, \mbox{IN}_{(VL)}, \mbox{IN}_{(WL)} - \mbox{COM}_{(L)} \end{array}$		0 ~ 0.65	5	V
Input OFF Threshold Voltage	V <sub>IN(OFF)</sub>	$\begin{array}{l} \mbox{Applied between IN}_{(UH)}, \mbox{IN}_{(VH)}, \mbox{IN}_{(WH)} - \\ \mbox{COM}_{(H)}, \mbox{IN}_{(UL)}, \mbox{IN}_{(VL)}, \mbox{IN}_{(WL)} - \mbox{COM}_{(L)} \end{array}$		4 ~ 5.5		V

**2nd Notes:** 8. Motion SPM<sup>®</sup> 2 product might not make response if the  $PW_{IN(OFF)}$  is less than the recommended minimum value.

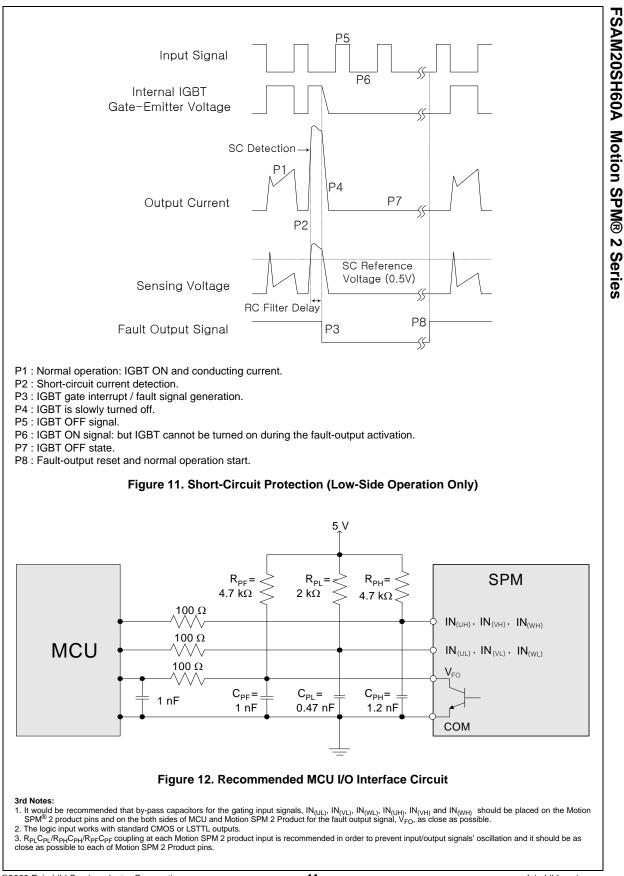


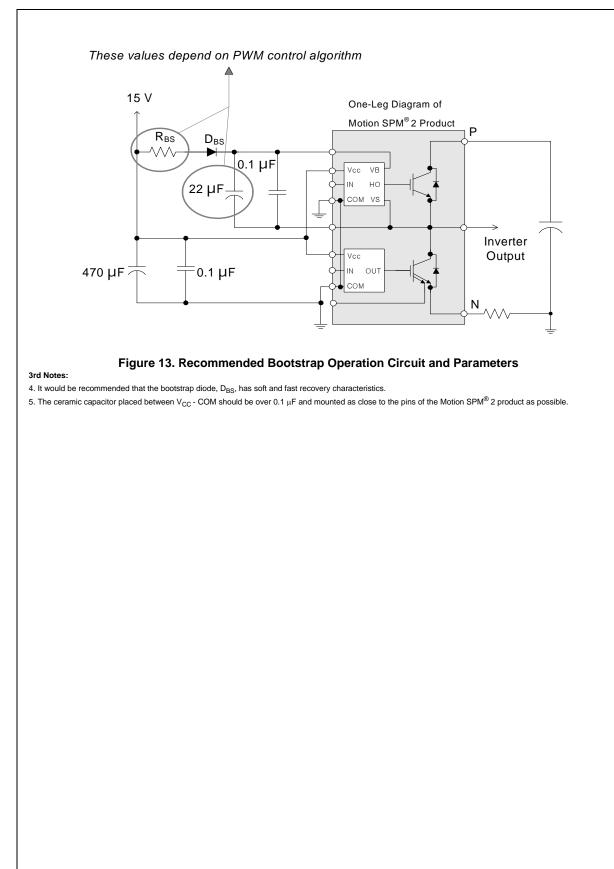


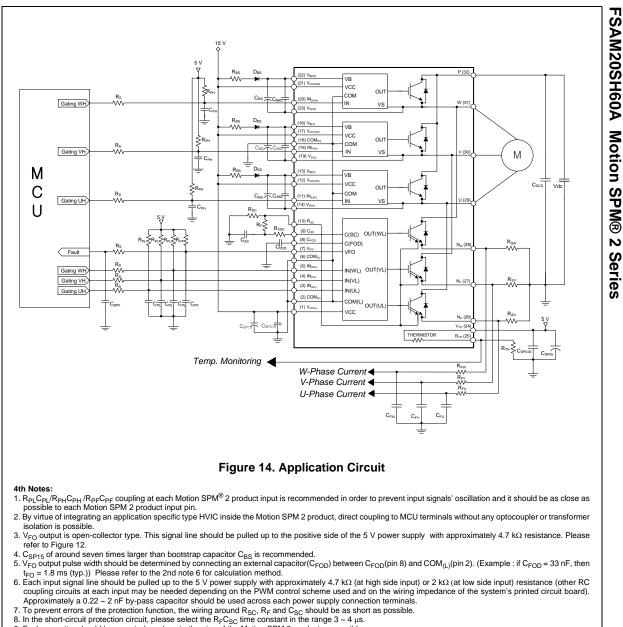
FSAM20SH60A Rev. C8

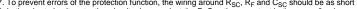
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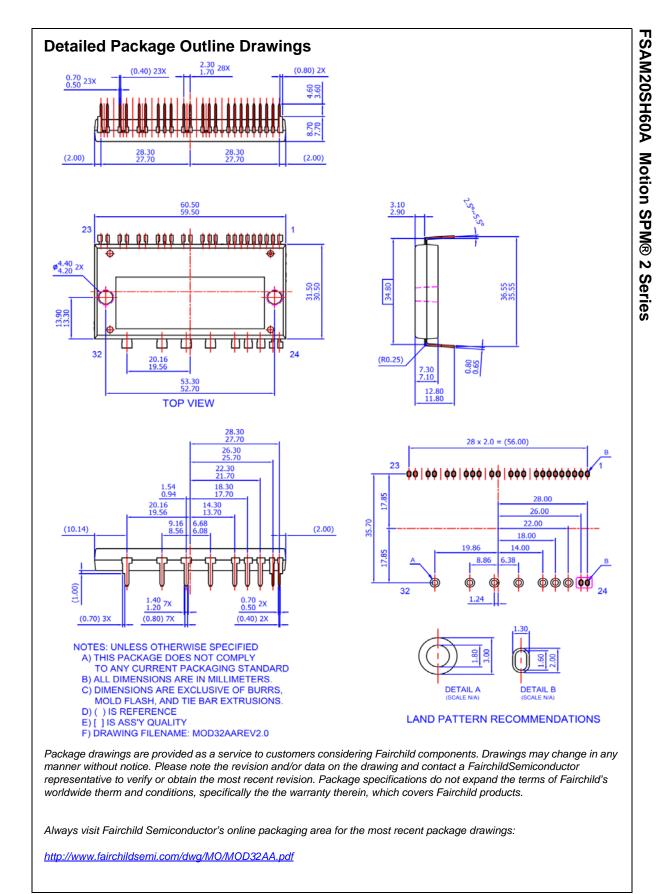




- 9. Each capacitor should be mounted as close to the pins of the Motion SPM 2 product as possible. 10. To prevent surge destruction, the wiring between the smoothing capacitor and the P & N pins should be as short as possible. The use of a high frequency non-
- inductive capacitor of around 0.1 ~ 0.22  $\mu\text{F}$  between the P&N pins is recommended. 11. Relays are used at almost every systems of electrical equipments of home appliances. In these cases, there should be sufficient distance between the MCU and the relays. It is recommended that the distance be 5 cm at least.

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SPM

STEALTH

SuperFET<sup>6</sup>

SuperSOT™-3

SuperSOT™-6

SuperSOT<sup>™</sup>-8

SupreMOS

SvncFET<sup>11</sup>

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury of the user.

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MillerDrive<sup>TI</sup>

MotionMax<sup>11</sup>

mWSaver

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Ultra FRFET™

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VisualMax<sup>Th</sup>

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<b>Datasheet Identification</b>	Product Status	Definition
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